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(D ated: A pril 14, 2024)

We report conductance measurements of ballistic one-dimensional (1D) wires defined in G aAs/A G aAs heterostructures in an in-plane magnetic eld, B. When the Zeeman energy is equal to the 1D subband energy spacing, the spin-split subband N " intersects (N + 1)#, where N is the index of the spin-degenerate 1D subband. At the crossing of N = 1" and N = 2# subbands, there is a spontaneous splitting giving rise to an additional conductance structure evolving from the 1:5 ($2e^2=h$) plateau. W ith further increase in B, the structure develops into a plateau and lowers to $2e^2=h$. W ith increasing temperature and magnetic eld the structure shows characteristics of the 0.7 structure. Our results suggest that at low densities a spontaneous spin splitting occurs whenever two 1D subbands of opposite spins cross.

PACS num bers: 71.70.-d, 72.25 D c, 73.21 H b, 73.23 A d

Studies of ballistic transport in one dimension (1D) have shown that a spontaneous spin splitting m ay occur at zero m agnetic eld, as indicated by a conductance structure at 0:7 ($2e^2=h$), which drops to 0:5 ($2e^2=h$) in an in-plane m agnetic eld[1]. This so-called 0.7 structure is widely reported in various types of ballistic 1D w ires de ned in G aA s[1, 2, 3, 4]and Si heterostructures[5]. In some cases, at very low electron densities a structure has been observed at 0:5 ($2e^2=h$) at zero m agnetic eld which strengthened with in-plane m agnetic eld[6], indicating a com plete spin polarisation [7, 8].

By studying Zeem an splitting of 1D subbands, it was shown that the 0.7 structure is accompanied by an enhancement of the Lande g-value as the 1D subbands are depopulated, and the energy dierence between the spinsplit 1D subbands tends to a nite value at zero magnetic eld [1]. The conductance plateau at $0.5 (2e^2=h)$, either observed in zero magnetic eld or induced by Zeem an effect, rises to $0.6 (2e^2=h)$ with increasing temperature[9]. None of these characteristics can be explained within a single particle model. As the situation is dynamic, for short ballistic 1D wires, zero- eld spin splitting may not be in con ict with the theorem of Lieb and M attis[10].

The discovery of the 0.7 structure in ballistic 1D wires has stimulated much theoretical work in one-dimension, som e of which focused on zero-eld spin polarisation [11, 12, 13], spin density wave formation [14], pairing of electrons[15], singlet-triplet form ation [16], K ondo-like interactions[4, 17, 18], and electron-phonon e ects[19]. Experimental studies [1, 2, 3] of the 0.7 structure have, in general, indicated that due to a spin splitting at zero magnetic eld, a complex many-body state may exist in a ballistic 1D constriction. In order to further study the role of spin, a strong magnetic eld is applied parallel to a quantum wire to produce large Zeem an splitting and induce crossings between spin-split 1D subbands [20]. In this work, we show that at the crossing of Zeem an-split 1D subbands of opposite spins and di erent spatial wavefunctions, a spontaneous splitting sets in, giving rise to new conductance structures exhibiting characteristics of the 0.7 structure; we call this new structure a 0.7 ana-

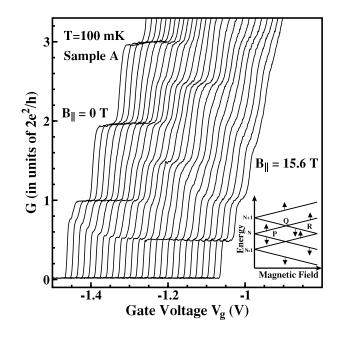


FIG.1: D i erential conductance, G (V_g), traces at B_k incremented in steps of 0.6 T.For clarity, successive traces are o – set horizontally. Inset: Schem atic energy diagram for a linear Zeem an splitting of 1D subbands and subsequent crossings.

bgue. W e have observed such 0.7 analogues in eight sam ples, with m agnetic eld applied in both in-plane directions.

Split-gate devices were de ned by electron beam lithography on a Hall bar etched from a high mobility GaAs/Al_xGa_{1 x} As heterostructure. Samples A and B used in this work have a length 0.4 m and widths 0.6 m and 0.5 m. The two-dimensional electron gas (2DEG) formed 292 nm below the surface has a mobility of 1:1 10^6 cm²/Vs and a carrier density of 1:15 10^{11} cm². Conductance measurements were performed in a dilution refrigerator using an excitation voltage of 10 V at 77 Hz. The samples were mounted with the magnetic eld, B_k, parallel to the current direction.

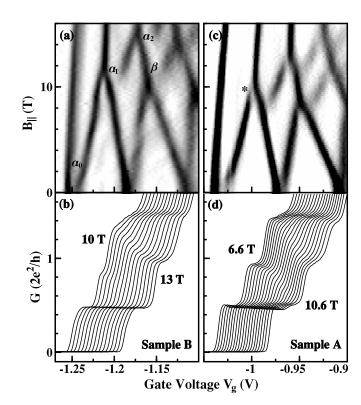


FIG.2: (a) G reyscale plot of transconductance, $dG = dV_g$, as a function of V_g and B_k for sam ple B. (b) G (V_g) traces (o set horizontally) for $B_k = 10$ T to 13 T incremented by 0.2 T (sam ple B, di erent cool-down). (c) G reyscale plot as in (a), for sam ple A. (d) G (V_g) traces as in (b), for sam ple A.

By monitoring the Hall voltage, the out-of-plane m isalignment was measured to be less than 0.5 $\,$.

Figure 1 shows di erential conductance $G = \frac{dI}{dV}$ traces, m easured as a function of split-gate voltage V_g at xed magnetic elds, B_k. The inset shows a schematic illustration of linear Zeem an splitting of 1D energy subbands for a parabolic potential con nem ent. The left trace of the main gure shows conductance plateaus quantised at N (2e²=h) and the 0.7 structure at $B_k = 0.A \times B_k$ is increm ented to 15.6 T (right trace), the overall conductance characteristics undergo three m a pr changes. These correspond to P, Q and R in Fig. 1 inset. Firstly, each spindegenerate 1D subband N splits into two, N " and N # (see P in the inset), and new conductance plateaus appear at half-integer values of 2e²=h. Secondly, with further increase of B_k, the half-integer plateaus strengthen and integer plateaus weaken. W hen the Zeem an energy, g $_{\rm B}$ B $_{\rm k}$, is equal to the subband energy spacing, $E_{N;N+1}$, integer plateaus disappear. This happens when the split levels, for example, N " and (N + 1)# converge and pass through a crossing point (see Q in the inset). Finally, with further increase of B_k, half-integer plateaus weaken and integer plateaus reappear as the N " and (N + 1) # diverge again after the crossing (see R in the inset). For example, the plateau at 1:5(2e²=h) weakens

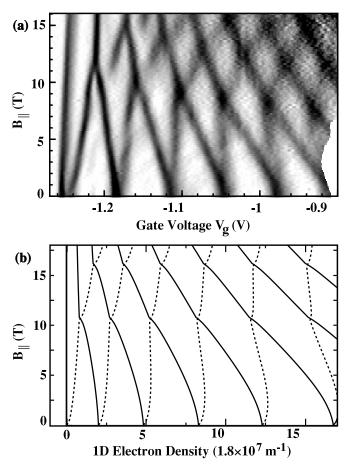


FIG.3: (a) G reyscale plot of $dG = dV_g$ as a function of V_g and B_k for sample B, showing the splitting of ve 1D subbands. (b) C alculated Zeem an splitting with diam agnetic shift of the 1D subbands. The solid lines represent parallel spin and the dotted lines represent anti-parallel spin.

and the $2e^2$ -h plateau reappears for $B_k > 8 T$. How ever, this is accompanied by the evolution of a weak structure from the edge of the 1.5 ($2e^2$ -h) plateau, which gradually low ers to $2e^2$ -h and develops into a plateau. This resem bles the evolution of the 0.7 structure to 0.5 ($2e^2$ -h) with increasing B_k . For this reason, we call the structure at the crossing a 0.7 analogue. It may be noted that the reappearing $2e^2$ -h plateau now carries the opposite spin to that before crossing. The low est subband 1#, how ever, does not encounter a crossing; therefore the plateau at 0.5 ($2e^2$ -h) is intact, and does not change its spin.

The evolution of conductance characteristics with the splitting of 1D subbands in B_k can be clearly represented in a grey-scale plot of the transconductance dG =dV_g, obtained by numerical di erentiation of G (V_g) characteristics. Figure 2 (a) shows dG =dV_g plots of sample B as a function of B_k and V_g . White regions represent low transconductance (plateaus in G (V_g)) and the dark thick lines correspond to high transconductance (transitions between plateaus). Each dark line splits into two as B_k

increases. This can be interpreted as the splitting of each 1D subband into two subbands of opposite spins as show n by P in the Fig. 1 inset. On the left of Fig. 2(a), for N = 1, there are two distinct dark lines at $B_k = 0$. The white region between these two dark lines represents the 0.7 structure, marked by $_0$. As the gap between the N = 1 and N = 1" widens with B_k , the 0.7 structure evolves into a plateau at $0.5 (2e^2=h)$ and the white region $\begin{pmatrix} 0 \end{pmatrix}$ in Fig.2 (a) broadens. At B_k 11 T, dark lines corresponding to N = 1" and N = 2# subbands cross. A fter the crossing, the line N = 1" shows a discontinuous shift of $V_q = 23 \text{ mV}$ from the crossing point, marked by 1. This discontinuity in the dark line N = 1" corresponds to the appearance of the 0.7 analogue. Figure 2(b) shows G (V_q) traces horizontally) in the vicinity of $_1$ from a di erent cool-down of the sam ple, highlighting the evolution of the 0.7 analogue from the edge of $1.5(2e^2=h)$ plateau to $2e^2 = h w$ ith increasing B_k . It is observed that the 1:5 (2e²=h) plateau, though weakening, rem ains visible when the 0.7 analogue evolves.

The discontinuous evolution of the right-moving dark lines ("-spin subbands) can also be observed at the crossing of N = 2" with N = 3# lines marked by , and at the second crossing of N = 1" with N = 3# line, m arked by 2. Figure 2 (c) and (d) show results of sample A in a di erent cool-down from that of Fig.1. In addition to the splittings at the crossing of peaks as observed in sam ple B, in this case there is also a splitting just before the crossing of N = 1" and N = 2# peaks, marked by an asterisk in Fig 2 (c). In one of the cool-downs, sample B also showed a weak splitting before the crossing. It is not clear whether this splitting marked by asterisk is related to $_1$, the 0.7 analogue. It may be observed that this corresponds to a slower rate of suppression of the $2e^2 = h$ plateau (1"-subband) in sample A with B_k as shown in Fig. 2 (d), compared to sample B in Fig. 2 (b).

In the following, we suggest that the main features of our observations arise from strong electron-electron interactions. To clarify this, we rst describe the expected behaviour in the case of non-interacting electrons. In particular, we show that the diam agnetic shifts of the subband energies in an in-plane magnetic eld have only a very limited in uence on the most important features of our observations.

Figure 3 (a) shows a greyscale plot of sam ple B with m any occupied 1D subbands, part of which is shown in Fig. 2 (a). Figure. 3 (b) shows the positions of the calculated transconductance peaks as a function of electron density and B_k for a m odel of non-interacting electrons in an in nite 1D w ire. Thism odel includes the diam agnetic e ects with B_k , assum ing parabolic con nem ent in the transverse and vertical (quantum well) directions with subband spacings of 1.85 m eV and 15 m eV [21] respectively. A g-value of 1.9 is used in thism odel in accordance with the value m easured at low B_k in our sam ples.

If one assumes that the electron density in the wire is linearly related to V_g , then Figs. 3(a) and (b) can be compared directly. C learly the model of non-interacting

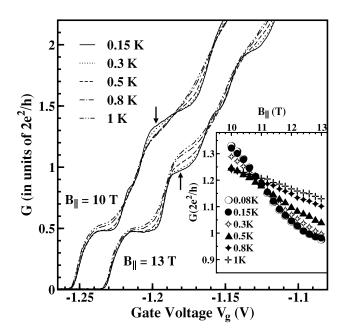


FIG. 4: Temperature dependence of G (V_g) for sample B (sam e cool-down as Fig.2(b)) at 10 T and 13 T. Inset: The height of the 0.7 analogue as a function of B_k for various temperatures.

electrons accounts well for the general trends in the evolution of the transconductance peaks with V_g and B_k . However, the model cannot capture the appearance of discontinuities in the positions of the transconducance peaks at the crossings, 1, 2, and in Fig. 2. As we have described above, these are the regions where the conductance displays the 0.7 analogues.

Figure 4 shows the tem perature dependence of the 0.7 analogue at the rst crossing of 1" and 2# subbands. A de ning characteristic of the 0.7 structure is its unusual tem perature dependence. In addition, at low tem peratures, the 0.7 structure becomes well-de ned only at low electron densities [6]. For a higher 1D density, a higher tem perature (typically, T 1 K in GaAs splitgate devices [1]) is required to induce the 0.7 structure [2]. At high B_k , it is well-known that the 0.7 structure develops into a plateau at $0.5(2e^2=h)$; how ever with an increase in T, the plateau rises to $0.6(2e^2=h)[9]$. These trends in the tem perature dependence of the 0.7 structure and 0:5 (2e²=h) plateau are also observed in the new 0.7 analogue structure at $B_k = 10$ T and $2e^2 = h$ plateau at $B_k = 13 \text{ T}$. Figure 4 shows that, at $B_k = 10 \text{ T}$, the 0.7 analogue present just below $1:5(2e^2=h)$ (shown by a down-arrow) drops as T rises; but at $B_k = 13$ T, the plateau at 2e²=h (shown by an up-arrow) rises with increasing T. In the inset of Fig. 4, conductance of the 0.7 analogue is plotted as a function of B_k for a range of tem peratures. This data com pares well to the tem perature dependence of the 0.7 structure [9], showing the crossover of G as a function of T at a characteristic B_k .

N on-quantised conductance structures can be due to a change in the transm ission probability caused by scattering or a many-body e ect in the 1D channel. We have observed 0.7 analogues in eight sam ples, and they are independent of cool-downs, and occur only at the crossing of spin-split subbands of opposite spins. Due to the high reproducibility of the 0.7 analogues, a disorder-induced scattering e ect can be discounted.

W hen two energy levels are brought together, an anticrossing m ay occur. However, this depends on the symmetry of the two wavefunctions. In our case, the two 1D levels that cross in B_k have di erent spins and subband indices; therefore such anticrossings should be very weak. Experim entally, we do not observe anticrossings of 1D subbands, rather a gap form s abruptly after the crossing. As in the case of the 0.7 structure, we believe that the new 0.7 analogue is a consequence of strong exchange interactions. In the form er case, there is a lifting of the zero-eld spin-degeneracy, whereas in the latter case, the degeneracy at the crossing point is lifted. W e can quantify the strength of the exchange interactions by m easuring the gate voltage splitting at 1. From dc source-drain bias calibration [22], $_1$ is measured to be 0.5 m eV, which is a third of the subband spacing (E $_{1,2}$ = 1:6 m eV) at zero magnetic eld.

G iven the strong sim ilarity between the 0.7 analogue and the 0.7 structure, we consider whether theories for the 0.7 structure could apply to our results. A recently proposed electron-phonon scattering mechanism for the 0.7 structure [19] cannot account for the observed 0.7 analogue. C onsider F ig. 2 (b): if the strong 0.7 analogue in these traces were the result of a conductance suppression caused by electron-phonon scattering, then one should 4

expect at least as strong a suppression below the spin-polarised 0.5 ($2e^2=h$) plateau; there is no such indication.

The behaviour of the 0.7 analogue does not seem to be consistent with the most sim ple extension of a proposed K ondo model" for the 0.7 structure[17] to the present situation { in which a K ondo in purity forms from quasibound states of the 1" and 2# levels which become degenerate at some non-zero B_k. In this model, one would expect the 0.7 analogue feature to fall onto the $2e^2=h$ plateau as B_k is increased or decreased away from the point of degeneracy in either direction. In contrast, the 0.7 analogue evolves asymmetrically about the midpoint of the crossing. A detailed analysis within the K ondo model will be considered in a later publication.

To conclude, we have observed the crossings of spinsplit 1D subbands of di erent spins and spatial wavefunctions in a 1D electron gas. At crossings, there is a spontaneous splitting giving rise to new conductance structures. There are no indications of anticrossings, but an energy splitting m ay occur whenever two 1D subbands of opposite spin are nearly degenerate. The magnetic eld and tem perature dependences show that the new structures strongly resemble the zero- eld 0.7 structure. We believe that these 0.7 analogue structures m ay provide the key to a fuller understanding of the role of electron-electron interactions in ballistic 1D w ires.

W e thank J.T.N icholls, D.K hm elnitskii, V.Tripathi, and C.J.B.Ford for useful discussions. This work was supported by EPSRC, UK.KJT acknow ledges support from the Royal Society.

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